



# SBE808 — Schottky Barrier Diode 15V, 1A Rectifier

## Applications

- High frequency rectification (switching regulators, converters, choppers).

## Features

- Small switching noise.
- Low leakage current and high reliability due to planar structure.
- Ultrasmall package permitting applied sets to be small and slim.

## Specifications

**Absolute Maximum Ratings** at Ta=25°C (Value per element)

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		15	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		17	V
Average Output Current	IO		1	A
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	10	A
Junction Temperature	Tj		-55 to +150	°C
Storage Temperature	Tstg		-55 to +150	°C

**Electrical Characteristics** at Ta=25°C (Value per element)

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Reverse Voltage	VR	IR=0.1mA	15			V
Forward Voltage	VF1	IF=0.5A		0.43	0.48	V
	VF2	IF=1A		0.49	0.54	V
Reverse Current	IR	VR=6V			3.0	μA
Interterminal Capacitance	C	VR=10V, f=1MHz		20		pF
Reverse Recovery Time	trr	IF=IR=100mA, See specified Test Circuit.			10	ns
Thermal Resistance	Rth(j-a)	Mounted on a ceramic board (600mm <sup>2</sup> X0.8mm)		185		°C / W

Marking : SE

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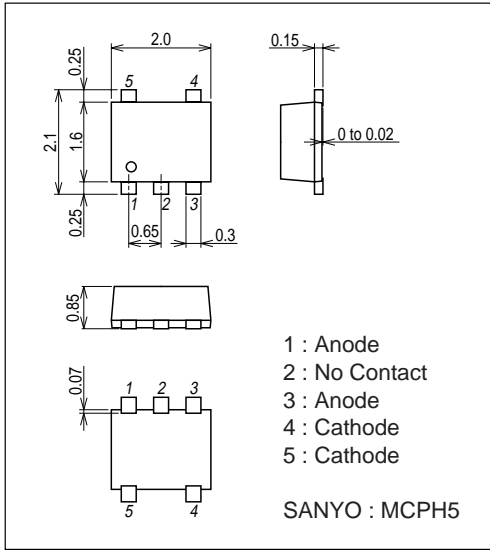
**SANYO Semiconductor Co., Ltd.**

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

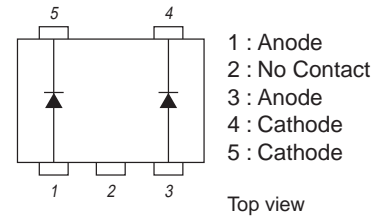
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Package Dimensions

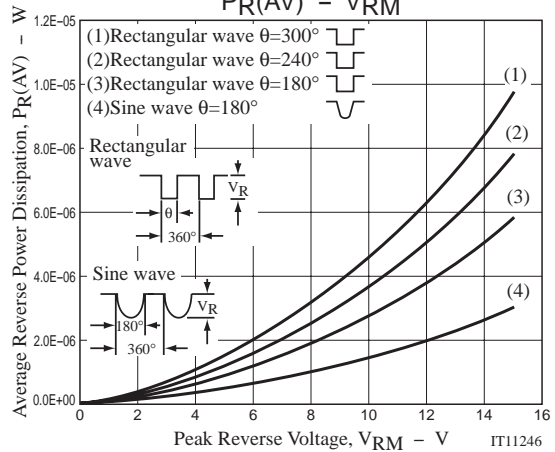
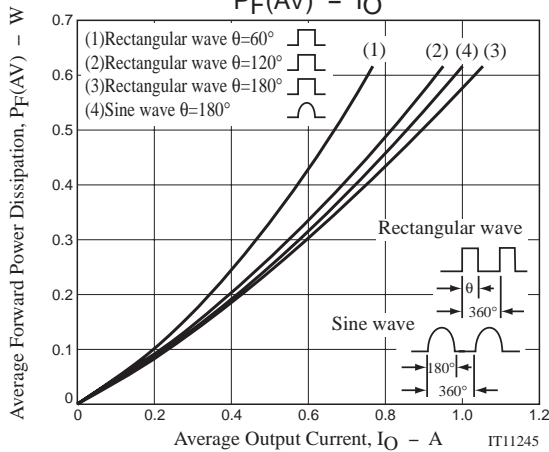
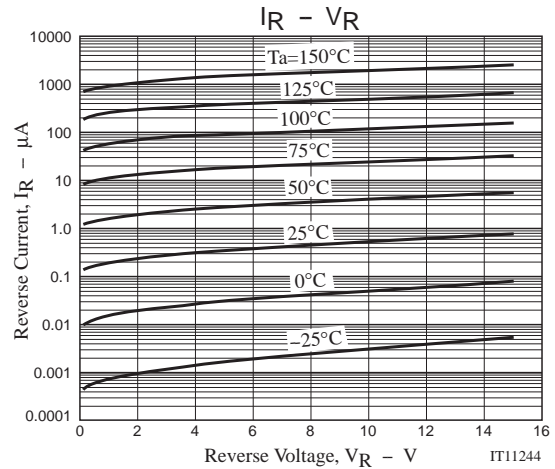
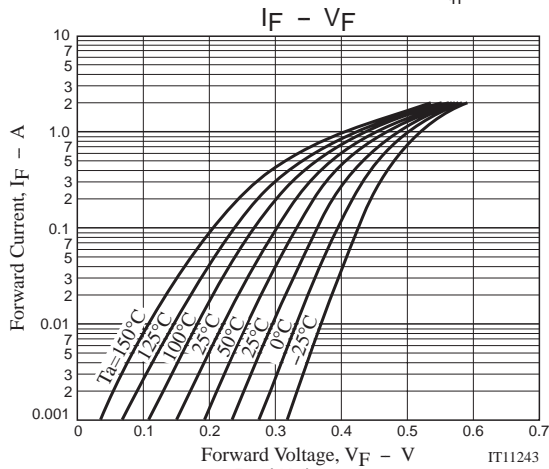
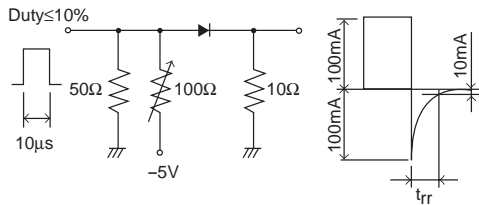
unit : mm (typ)  
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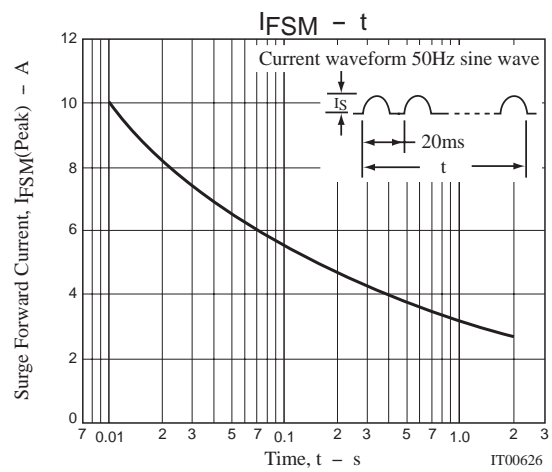
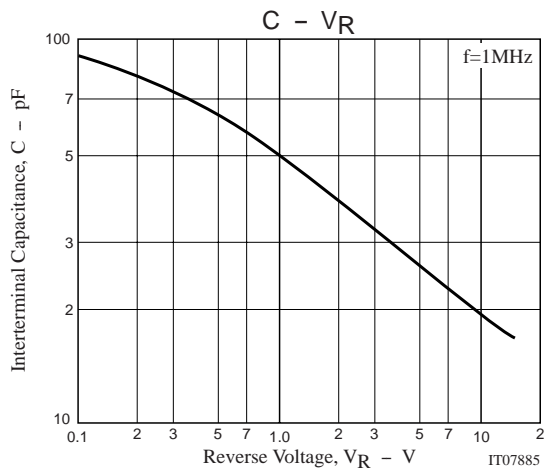


Electrical Connection



$t_{rr}$  Test Circuit





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